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Micro- and Nanotechnology of Wide Bandgap Semiconductors

Guest Editors:

Message from the Guest Editors

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Deadline for manuscript submissions: closed (31 October 2020)



Dear Colleagues,

Impressive progress in GaN technology over the last 25 years has been driven by a continuously growing need for more advanced systems and new challenges continue to arise and need to be solved. The lighting industry, RF defense industry, and 5G mmWave telecommunication systems are driving forces for further intense research in order to reach the full potential of GaN-based semiconductors.

The specific topics of this Special Issue include the following: GaN single crystalline substrates for electronic devices by ammonothermal and HVPE methods, drift layers by HVPE, MOVPE, and MBE, advances in ion implantation of GaN and related materials, high-pressure processing (lattice reconstruction) of ion-implanted GaN (Mg and Be), novel metallization schemes for ohmic contacts, thermal issues in GaN HEMTs, AlGaN/GaN HEMTs on native substrates, laser diodes based on MOVPE and MBE epitaxy including vertically integrated devices with tunnel junctions, monolithic green-blue and red-greenblue LED structures for highly efficient displays, external cavity laser diodes for quantum technologies applications, porous GaN for supercondensators, and III-nitride nanowires for LEDs.







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Message from the Editor-in-Chief

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